




**SPECIFICATION SHEET**

<b>SPECIFICATION SHEET NO.</b>	N1004- DFN10063L0S52L
<b>DATE</b>	Oct. 04, 2021
<b>REVISION</b>	A0
<b>DESCRIPTION</b>	<p>SMD Plastic-Encapsulate ESD Protection Diodes, DFN1006-3L series, 3 pads ESD0502L Type, Ultra -Low Capacitance ESD Protection Diodes</p> <p><b>Reverse Working Voltage: 5.0V, Clamping Voltage : 10.0V Max.@ 1.0A</b></p> <p>Operating Temp. Range -55°C ~+125°C, Package in Tape/Reel, 10,000pcs/Reel RoHS/RoHS III compliant</p>
<b>CUSTOMER</b>	
<b>CUSTOMER PART NUMBER</b>	
<b>CROSS REF. PART NUMBER</b>	
<b>ORIGINAL PART NUMBER</b>	MDD ESD0502L
<b>PART CODE</b>	DFN10063L0S52L

<b>VENDOR APPROVE</b>			
Issued/Checked/Approved			
DATE: Oct. 04, 2021			

<b>CUSTOMER APPROVE</b>	
DATE:	

**SMD ESD PROTECTION DIODES DFN1006-3L SERIES**

**MAIN FEATURE**



- Peak Power Dissipation 60W (8/20µs)
- Transient protection for high speed data lines
- IEC61000-4-2 (ESD) ±15kV (air), ±8kV (contact)
- IEC61000-4-4 (EFT) 40A (5/50ns)
- Cable Discharge Event (CDE)
- Small package L1.0\*W0.6\*H0.5mm
- Protect two data lines
- Low clamping voltage
- Low leakage current
- Low Capacitance: 0.2pF Typical (I/O – I/O)

**APPLICATION**

- Serial ATA
- Desktops, Servers and Notebooks
- PCI Express
- MDDI Ports
- USB Data Line Protection
- Display Ports
- Digital Visual Interfaces (DVI)

**PART CODE GUIDE**

**RFQ**  
Request For Quotation

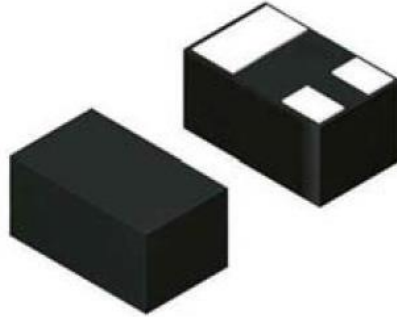
<b>DFN10063L</b>	<b>0</b>	<b>S</b>	<b>52L</b>
1	2	3	4

- 1) **DFN10063L**: SMD Plastic-Encapsulate ESD Protection Diodes, DFN1006-3L series, 3 pads
- 2) **0**: Type code for original part number ESD0502L
- 3) **S**: Package code, Package in Tape/Reel, 10000pcs/Reel
- 4) **52L**: Marking code “52L” on the case surface, Different Marking for different specification.

**SMD ESD PROTECTION DIODES DFN1006-3L SERIES**

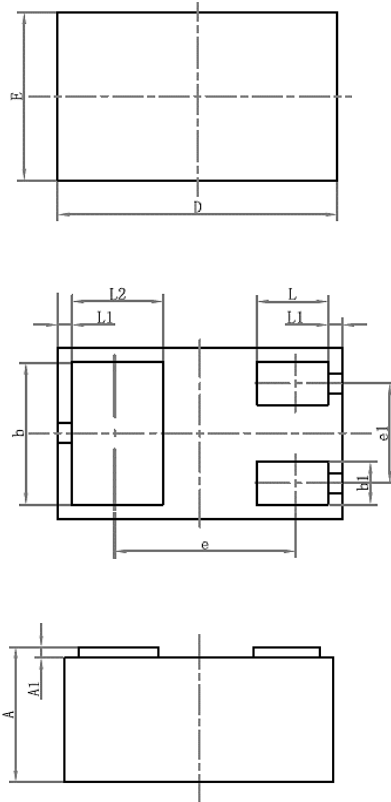
**DIMENSION (Unit: mm)**

Image for reference



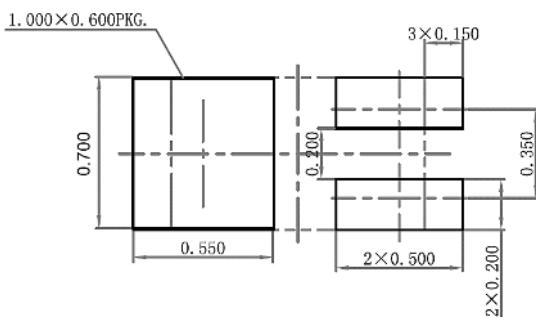
Marking: 52L

DFN1006-3L

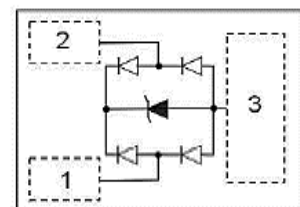


Symbol	Value ( mm )		
	Min.	Typ.	Max.
A	0.45		0.550
A1	0.010		0.10
D	0.95		1.05
E	0.55		0.650
b	0.45 Ref.		
b1	0.10		0.20
e	0.635 Ref.		
e1	0.30		0.4
L	0.20		0.3
L1	0.05 Ref.		
L2	0.20		0.3

**Recommend Pad Layout**



**Circuit Diagram**



**SMD ESD PROTECTION DIODES DFN1006-3L SERIES**

**MECHANICAL DATA**

Case	Terminals	Flammability Rating	Mounting Position	Weight per piece
JEDEC DFN1006-3L molded plastic body	Gold plated, solderable per MIL-STD-750, Method 2026	UL 94V-0	-	-

**ABSOLUTE MAX. RATINGS AT Ta=25 °C (unless otherwise specified)**

Parameter	SYMBOLS	VALUE	UNITS
		LIMIT	
ESD per IEC 61000-4-2 (Air)	V ESD	+/-20	KV
ESD per IEC 61000-4-2 (Contact)	V ESD	+/-20	KV
Peak Pulse power (t p = 8/20 μs waveform)	P PP	60	W
Lead Solder Temperature – Maximum (10 Second Duration)	T L	260 (10 sec.)	°C
Operating Temperature Range	TOPT	-55 ~+ 125	°C
Storage Temperature Range	T STG	-55 ~ +150	°C

Note: FR-5= 1.0\*0.75\*0.62 in.

**SMD ESD PROTECTION DIODES DFN1006-3L SERIES**
**ELECTRICAL CHARACTERISTICS ( Ta=25 °C unless otherwise specified)**

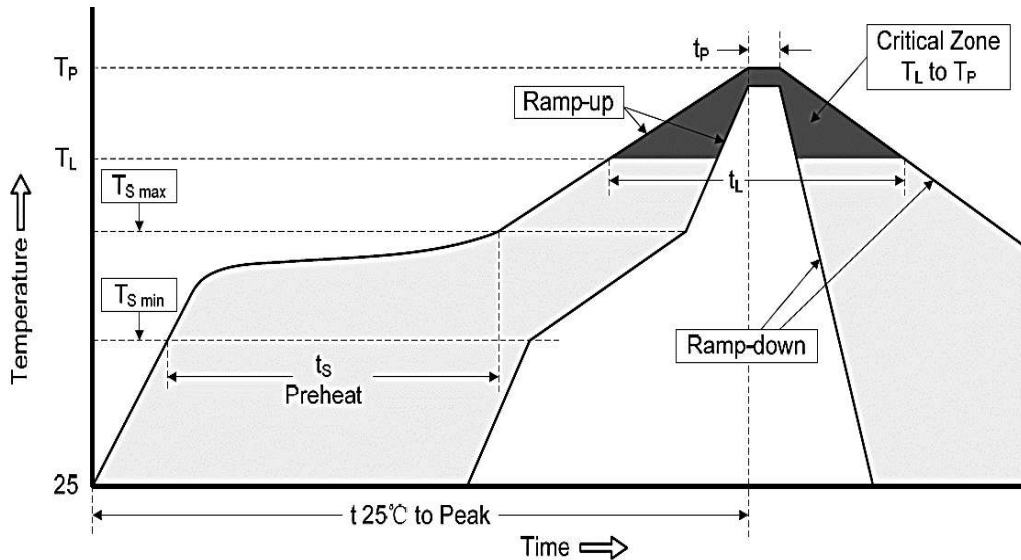
Parameter	SYMBOLS	VALUE			UNITS
		Min.	Typical	Max.	
<b>Reverse Working Voltage @ I/O pin to Ground</b>	V <sub>RWM</sub>			5.0	V
<b>Reverse Breakdown Voltage @ I<sub>T</sub> = 1.0mA Between I/O and GND</b>	V <sub>BR</sub>	6.0			V
<b>Reverse Leakage Current @V<sub>RWM</sub> = 5V Between I/O and GND</b>	I <sub>R</sub>			100	nA
<b>Clamping Voltage @ I<sub>PP</sub> = 1.0A, t<sub>p</sub> = 8/20μs Between I/O and GND</b>	V <sub>C</sub>			10.0	V
<b>Clamping Voltage @ I<sub>PP</sub> = 4.0A, t<sub>p</sub> = 8/20μs Between I/O and GND</b>	V <sub>C</sub>			15.0	V
<b>Forward Voltage @ I<sub>T</sub> = 10 mA Between I/O and GND</b>	V <sub>F</sub>			1.2	V
<b>Total Capacitance @ V<sub>R</sub> = 0 V, f = 1.0MHz Between I/O and GND</b>	C <sub>T</sub>		0.4	0.6	pF
<b>Total Capacitance @ V<sub>R</sub> = 0 V, f = 1.0MHz Between I/O and I/O</b>	C <sub>T</sub>		0.2	0.3	pF

**SMD ESD PROTECTION DIODES DFN1006-3L SERIES**
**RELIABILITY**

Number	Experiment Items	Experiment Method And Conditions	Reference Documents
1	Solder Resistance Test	Test 260°C± 5°C for 10 ± 2 sec. Immerse body into solder 1/16" ± 1/32"	MIL-STD-750D METHOD-2031.2
2	Solderability Test	230°C ±5°C for 5 sec.	MIL-STD-750D METHOD-2026.1 0
3	Pull Test	1 kg in axial lead direction for 10 sec.	MIL-STD-750D METHOD-2036.4
4	Bend Test	0.5Kg Weight Applied To Each Lead, Bending Arcs 90 °C ± 5 °C For 3 Times	MIL-STD-750D METHOD-2036.4
5	High Temperature Reverse Bias Test	TA=100°C for 1000 Hours at VR=80% Rated VR	MIL-STD-750D METHOD-1038.4
6	Forward Operation Life Test	TA=25°C Rated Average Rectified Current	MIL-STD-750D METHOD-1027.3
7	Intermittent Operation Life Test	On state: 5 min with rated IRMS Power Off state: 5 min with Cool Forced Air. On and off for 1000 cycles.	MIL-STD-750D METHOD-1036.3
8	Pressure Cooker Test	15 PSIG, TA=121°C, 4 hours	MIL-S-19500 APPENOIXC
9	Temperature Cycling Test	-55°C~+125°C; 30 Minutes For Dwelled Time 5 minutes for transferred time. Total: 10 cycles.	MIL-STD-750D METHOD-1051.7
10	Thermal Shock Test	0°C for 5 minutes., 100°C for 5minutes, Total: 10 cycles	MIL-STD-750D METHOD-1056.7
11	Forward Surge Test	8.3ms Single Sale Sine-wave One Surge.	MIL-STD-750D METHOD-4066.4
12	Humidity Test	TA=65°C, RH=98% for 1000 hours.	MIL-STD-750D METHOD-1021.3
13	High Temperature Storage life Test	150°C for 1000 Hours	MIL-STD-750D METHOD-1031.5

**SMD ESD PROTECTION DIODES DFN1006-3L SERIES**

**SUGGESTED REFLOW PROFILE (For Reference Only)**

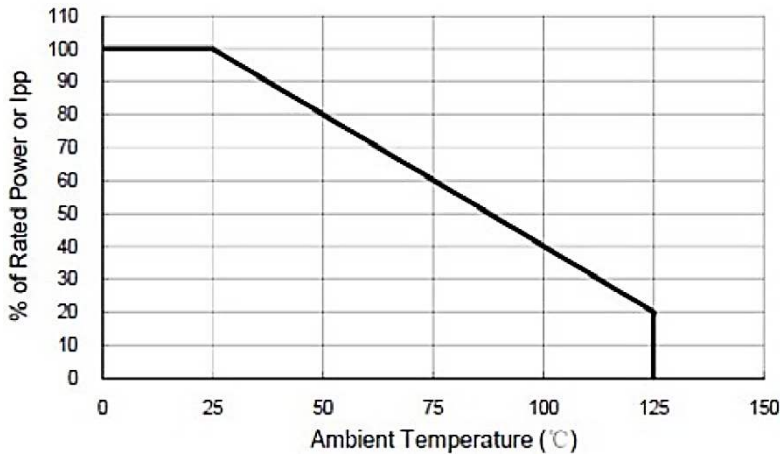


<b>Profile Feature</b>		Pb-Free Assembly
<b>Average Ramp-up Rate (Ts Max to Tp)</b>		3°C/second Max
<b>Preheat</b>	<b>Temperature Min (Ts Min.)</b>	150°C
	<b>Temperature Max (Ts Max.)</b>	200°C
	<b>Time (ts Min. to ts Max.)</b>	60 ~ 180 seconds
<b>Time maintained above</b>	<b>Temperature (T<sub>L</sub>)</b>	217°C
	<b>Time (t<sub>L</sub>)</b>	60 ~ 150 seconds
<b>Peak/Classification Temperature (T<sub>p</sub>)</b>		260 °C
<b>Time within 5°C of actual Peak Temperature (t<sub>p</sub>)</b>		20 ~ 40 seconds
<b>Ramp-down rate</b>		6 °C /Second Max.
<b>Time 25 °C to Peak Temperature</b>		8 minutes Max.
<b>Suggest reflow times</b>		3 Times Max.

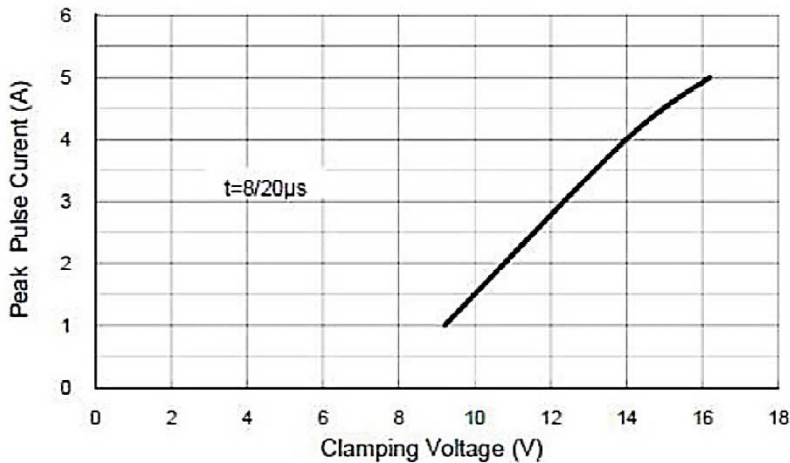
**SMD ESD PROTECTION DIODES DFN1006-3L SERIES**

**RATINGS AND CHARACTERISTIC CURVES (For Reference Only)**

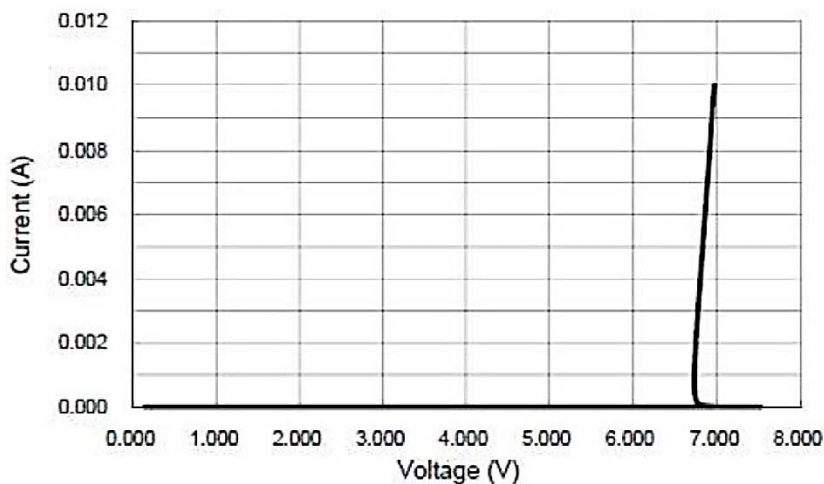
**Fig 1 Power Derating Curve**



**Fig 2 Clamping Voltage vs Peak Pulse Current**



**Fig 3 Voltage Sweeping**

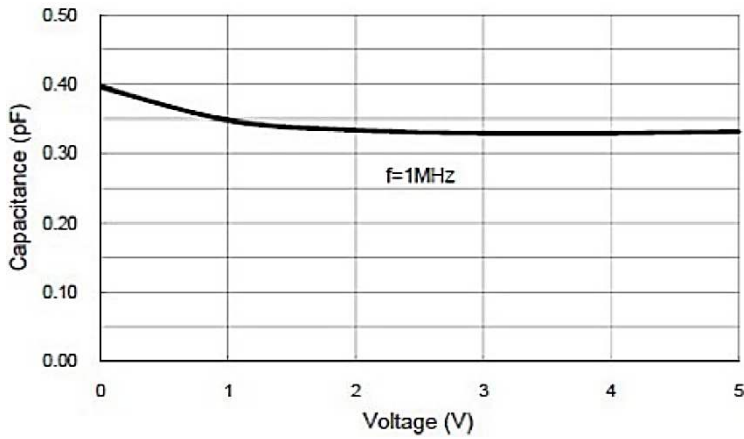




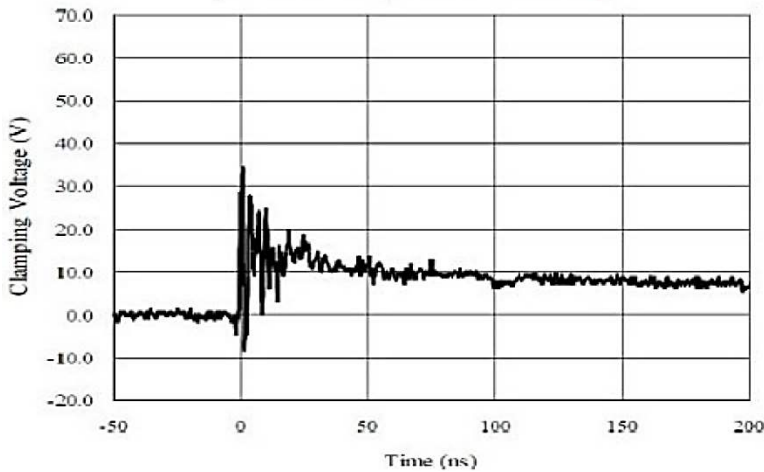
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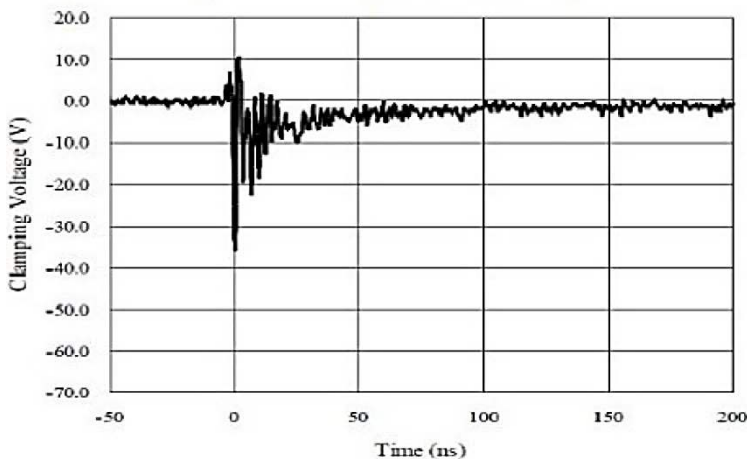
**Fig 4 Voltage vs Capacitance**



**Fig 5 ESD Clamping (+8kV Contact per IEC 61000-4-2)**



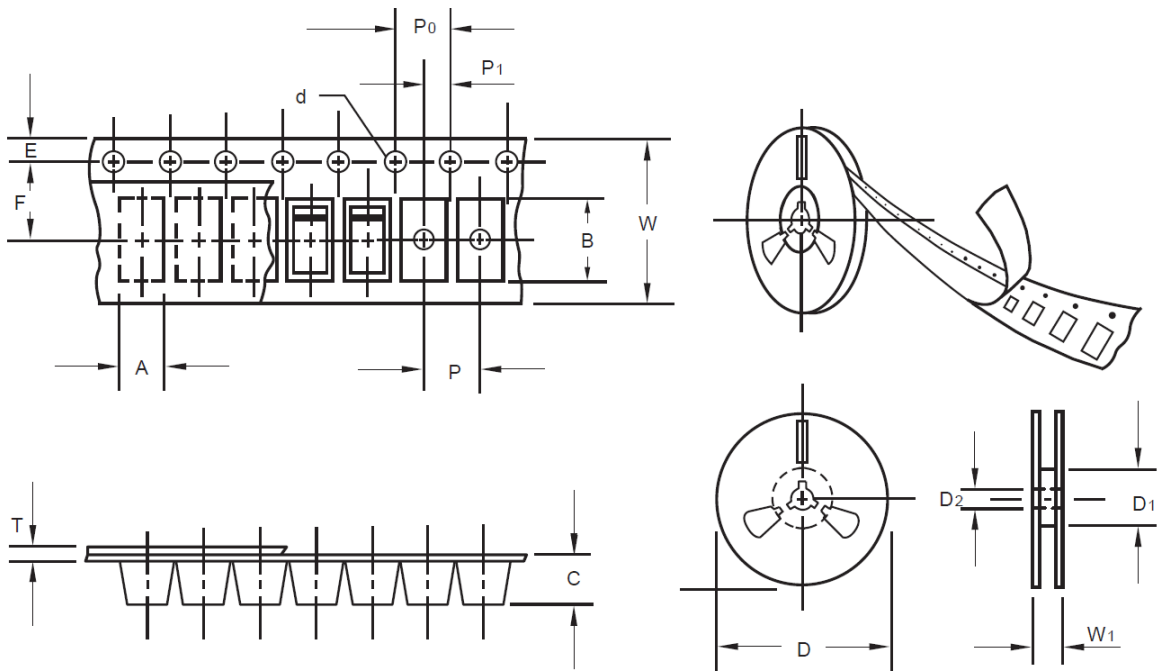
**Fig 6 ESD Clamping (-8kV Contact per IEC 61000-4-2)**



**SMD ESD PROTECTION DIODES DFN1006-3L SERIES**

**TAPE/REEL (Unit: mm)**

All Devices are packed in accordance with EIA standard RS-481-A and specifications.



Item	Symbol	Tolerance	DFN1006
Carrier width	A	0.1	2.10
Carrier Length	B	0.1	4.00
Carrier Depth	C	0.1	1.60
Sprocket hole	d	0.05	1.55
13"Reel outside diameter	-	-	-
13"Reel inner diameter	-	-	-
7"Reel outside diameter	D	2.0	178.00
7"Reel inner diameter	D1	Min.	50.00
Feed hole diameter	D2	0.5	13.00
Sprocket hole position	E	0.1	1.75
Punch hole position	F	0.1	3.50
Punch hole pitch	P	0.1	4.00
Sprocket hole pitch	P0	0.1	4.00
Embossment center	P1	0.1	2.00
Overall tape thickness	T	0.1	0.25
Tape width	W	0.3	8.15
Reel width	W1	1.0	10.50

**SMD ESD PROTECTION DIODES DFN1006-3L SERIES**

**SPQ PACKAGE for Reference**

Item	Unit	Value
Case Code		DFN1006-3L
Reel Size	Inch	7
Reel Size	mm	178
Tape Space	mm	/
SPQ /Reel	pcs	10000
Weigh /SPQ	LBS	
Weigh /SPQ	KGs	-
Qty. Per Box	pcs	20,000
Inner Box	Inch	L8.0*W8.0*H1.5

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